

# μA741QB Operational Amplifier

MIL-STD-883  
July 1986—Rev 2<sup>5</sup>

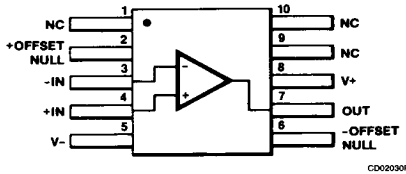
Aerospace and Defense Data Sheet  
Linear Products

### Description

The μA741QB is a high performance monolithic operational amplifier constructed using the Fairchild Planar Epitaxial process. It is intended for a wide range of analog applications. High common mode voltage range and absence of latch-up tendencies make the μA741QB ideal for use as a voltage follower. The high gain and wide range of operating voltage provide superior performance in integrator, summing amplifier, and general feedback applications.<sup>6</sup>

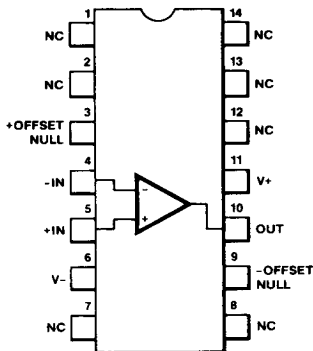
- No Frequency Compensation Required
- Short Circuit Protection
- Offset Voltage Null Capability
- Large Common Mode And Differential Voltage Ranges
- Low Power Consumption
- No Latch-Up

### Connection Diagram 10-Lead Flatpak (Top View)



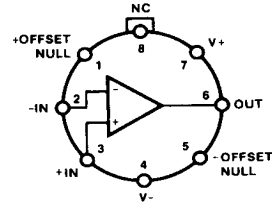
CD02030F

### Connection Diagram 14-Lead DIP (Top View)



CD02020F

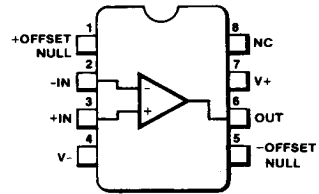
### Connection Diagram 8-Lead Can (Top View)



CD00751F

Lead 4 connected to case.

### Connection Diagram 8-Lead DIP (Top View)



CD00761F

### Order Information

Part No.	Case/ Finish	Package Code Mil-M-38510, Appendix C
μA741DMQB	CA	D-1 14-Lead DIP
μA741HMQB	GC	A-1 8-Lead Can
μA741FMQB	HA	F-4 10-Lead Flatpak
μA741RMQB	PA	D-4 8-Lead DIP

### JAN Product Available

10101	BCA	D-1 14-Lead DIP
10101	BCB	D-1 14-Lead DIP
10101	BGA	A-1 8-Lead Can
10101	BGC	A-1 8-Lead Can
10101	BHA	F-4 10-Lead Flatpak
10101	BHB	F-4 10-Lead Flatpak
10101	BPA	D-4 8-Lead DIP
10101	BPB	D-4 8-Lead DIP

**Absolute Maximum Ratings**

Storage Temperature Range	-65°C to +175°C
Operating Temperature Range	-55°C to +125°C
Lead Temperature (soldering, 60 s)	300°C
Internal Power Dissipation <sup>11</sup>	
Can and Flatpak	330 mW
DIP	400 mW
Supply Voltage	± 22 V
Differential Input Voltage	± 30 V
Input Voltage <sup>12</sup>	± 20 V
Short Circuit Duration <sup>13</sup>	Indefinite

**Processing:** MIL-STD-883, Method 5004**Burn-In:** Method 1015, Condition A, PDA calculated using Method 5005, Subgroup 1**Quality Conformance Inspection:** MIL-STD-883, Method 5005**Group A Electrical Tests Subgroups:**

1. Static tests at 25°C
2. Static tests at 125°C
3. Static tests at -55°C
4. Dynamic tests at 25°C
5. Dynamic tests at 125°C
6. Dynamic tests at -55°C
9. AC tests at 25°C
10. AC tests at 125°C
11. AC tests at -55°C

**Group C and D Endpoints: Group A, Subgroup 1****Notes**

1. 100% Test and Group A
2. Group A
3. Periodic tests, Group C
4. Guaranteed but not tested
5. When changes occur, FSC will make data sheet revisions available. Contact local sales representative for the latest revision.
6. For more information on device function, refer to the Fairchild Linear Data Book Commercial Section.
7.  $Z_1$  is guaranteed by  $I_{IB}$ :  $Z_1 = 4.0 V_T / I_{IB}$ .  $V_T = 26$  mV at 25°C, 34 mV at 125°C and 19 mV at -55°C.
8.  $P_c$  is guaranteed by  $I_{CC}$ :  $P_c = 30 I_{CC}$
9.  $V_{IR}$  is guaranteed by the CMR test.
10. BW is guaranteed by  $t_r$ :  $BW = 0.35 / t_r$ .
11. Rating applies to ambient temperatures up to 125°C. Above 125°C ambient, derate linearly at 150°C/W for the Can and Flatpak and 120°C/W for the DIP.
12. For supply voltages less than ±20 V, the absolute maximum input voltage is equal to the supply voltage.
13. Short circuit may be to ground or either supply. Rating applies to 125°C case temperature or 75°C ambient temperature.

# μA741QB

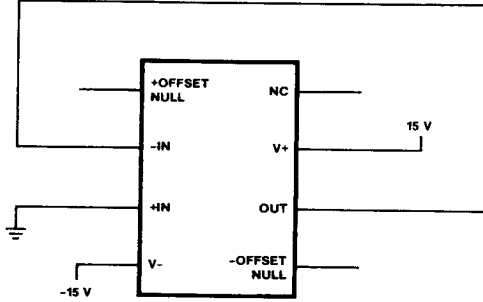
## μA741QB

**Electrical Characteristics**  $V_{CC} = \pm 15$  V, unless otherwise specified.

Symbol	Characteristic	Condition	Min	Max	Unit	Note	Subgrp
$V_{IO}$	Input Offset Voltage	$50 \Omega \leq R_S \leq 10 \text{ k}\Omega$ , $V_{CM} = 0$ V		5.0	mV	1	1
				6.0	mV	1	2,3
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Temperature Sensitivity	$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		15	$\mu\text{V}/^\circ\text{C}$	4	2
		$-55^\circ\text{C} \leq T_A \leq +25^\circ\text{C}$		15	$\mu\text{V}/^\circ\text{C}$	4	3
$V_{IO \text{ adj}}$	Input Offset Voltage Adjustment Range	$V_{CC} = \pm 20$ V	5.0		mV	1	1,2,3
$I_{IO}$	Input Offset Current	$V_{CM} = 0$ V		200	nA	1	1,2
				500	nA	1	3
$\Delta I_{IO}/\Delta T$	Input Offset Current Temperature Sensitivity	$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		1.0	nA/ $^\circ\text{C}$	4	2
		$-55^\circ\text{C} \leq T_A \leq +25^\circ\text{C}$		1.0	nA/ $^\circ\text{C}$	4	3
$I_{IB}$	Input Bias Current	$V_{CM} = 0$ V		340	nA	1	1
				500	nA	1	2
				1500	nA	1	3
$Z_I$	Input Impedance <sup>7</sup>		0.3		M $\Omega$	1	1
			0.2		M $\Omega$	1	2
$I_{CC}$	Supply Current			2.8	mA	1	1
				2.5	mA	1	2
				3.3	mA	1	3
$P_c$	Power Consumption <sup>8</sup>			85	mW	1	1
				75	mW	1	2
				100	mW	1	3
CMR	Common Mode Rejection	$V_{CM} = \pm 12$ V, $R_S = 50 \Omega$	70		dB	1	1,2,3
$V_{IR}$	Input Voltage Range <sup>9</sup>		$\pm 12$		V	1	1,2,3
PSRR	Power Supply Rejection Ratio	$\pm 5.0$ V $\leq V_{CC} \leq \pm 22$ V, $R_S = 50 \Omega$		150	$\mu\text{V}/\text{V}$	1	1,2,3
$I_{OS}$	Output Short Circuit Current			60	mA	1	1,2,3
$A_{VS}$	Large Signal Voltage Gain	$V_O = \pm 10$ V, $R_L = 2.0 \text{ k}\Omega$	50		V/mV	1	4
			25		V/mV	1	5,6
$V_{OP}$	Output Voltage Swing	$R_L = 10 \text{ k}\Omega$	$\pm 12$		V	1	4,5,6
		$R_L = 2.0 \text{ k}\Omega$	$\pm 10$		V	1	4,5,6
$TR(t_r)$	Transient Response	Rise Time		800	ns	3	9, 10, 11
		Overshoot		25	%	3	9, 10, 11
$TR(c_s)$							
BW	Bandwidth <sup>10</sup>		0.437		MHz	3	9, 10, 11
SR	Slew Rate	$V_{CC} = \pm 20$ V, $R_L = 2.0 \text{ k}\Omega$ , $A_V = 1.0$	0.3		V/ $\mu\text{s}$	3	9, 10, 11
$N_i$ (BB)	Noise Broadband	$V_{CC} = \pm 20$ V, BW = 5.0 kHz		15	$\mu\text{V}_{\text{rms}}$	4	9
$N_i$ (PC)	Noise Popcorn	$V_{CC} = \pm 20$ V, BW = 5.0 kHz		40	$\mu\text{V}_{\text{pk}}$	4	9

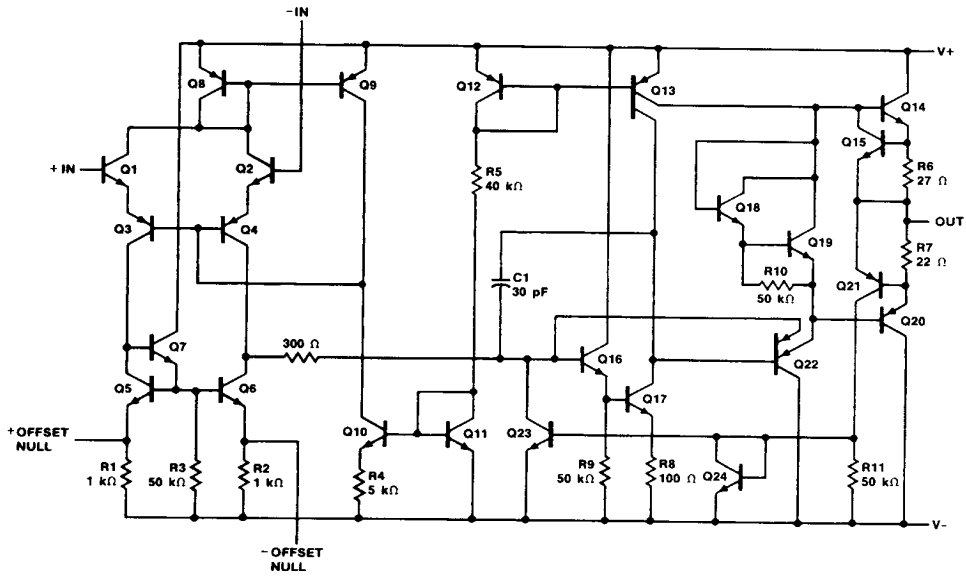
**Primary Burn-In Circuit**

(38510/10101 may be used by FSC as an alternate)



CR05190F

**Equivalent Circuit**



8000351F